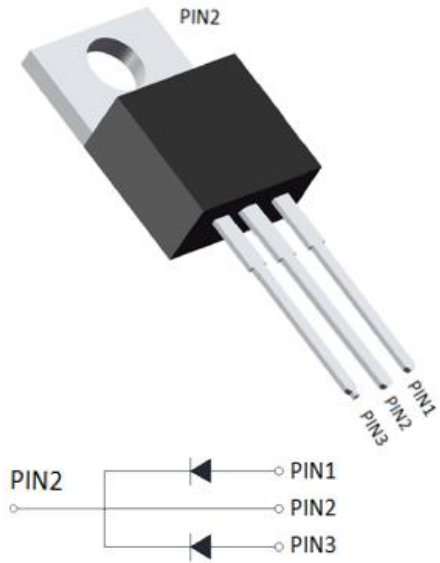


Schottky Diodes



Features

- High frequency operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Solder dip 275 °C max. 7 s, per JESD 22-B106

Typical Applications

Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

Mechanical Data

- **Package:** TO-220AB
Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** As marked

■ Maximum Ratings ($T_a=25^\circ\text{C}$ Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	MBRL10100CT
Device marking code			MBRL10100CT
Repetitive Peak Reverse Voltage	VRRM	V	100
Average Rectified Output Current @60Hz sine wave, R-load, $T_a=25^\circ\text{C}$	I _O	A	10
Surge(Non-repetitive)Forward Current @60Hz half sine-wave, 1 cycle, $T_a=25^\circ\text{C}$	I _{FSM}	A	100
Current Squared Time @ $1\text{ms} \leq t \leq 8.3\text{ms}$ $T_j=25^\circ\text{C}$	I ² t	A ² s	41
Storage Temperature	T _{stg}	°C	-55 ~ +150
Junction Temperature	T _j	°C	-55 ~ +150

■ Electrical Characteristics ($T_a=25^\circ\text{C}$ Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	MBRL10100CT
Maximum instantaneous forward voltage drop per diode	VFM	V	I _{FM} =5.0A	0.72
Maximum DC reverse current at rated DC blocking voltage per diode	I _{RRM1}	mA	V _{RM} =V _{RRM} $T_a=25^\circ\text{C}$	0.1
	I _{RRM2}		V _{RM} =V _{RRM} $T_a=100^\circ\text{C}$	20



MBRL10100CT

■ Thermal Characteristics ($T_a=25^\circ\text{C}$ Unless otherwise specified)

PARAMETER		SYMBOL	UNIT	MBRL10100CT
Thermal Resistance	Between junction and case	$R_{\theta J-C}$	$^\circ\text{C/W}$	2.0

■ Ordering Information (Example)

PREFERRED P/N	UNIT WEIGHT(g)	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
MBRL10100CT	Approximate 1.9	50	1000	5000	Tube

■ Characteristics (Typical)

FIG1: $I_o - T_c$ Curve

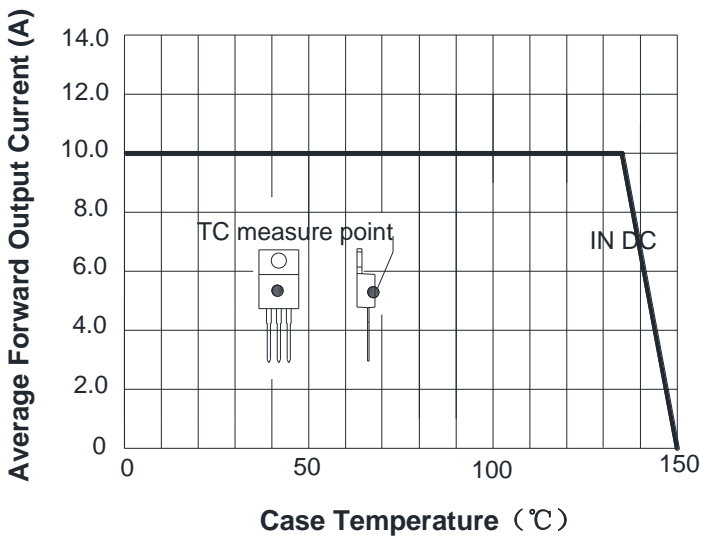


FIG2: Surge Forward Current Capability

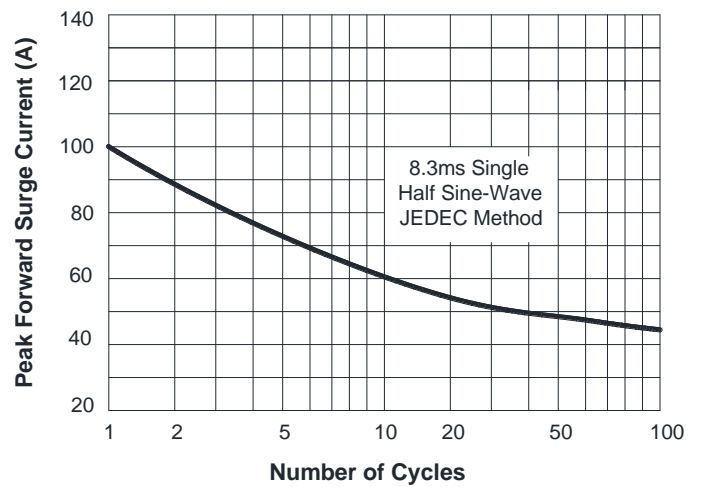


FIG3: Forward Voltage

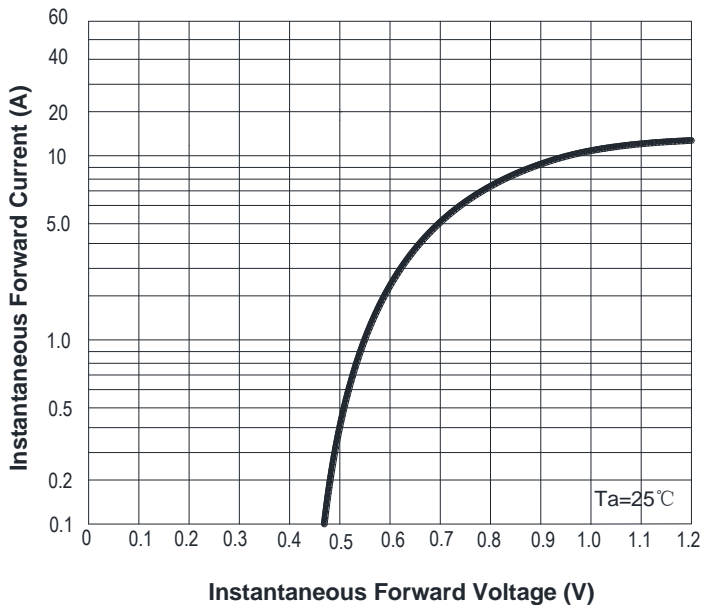
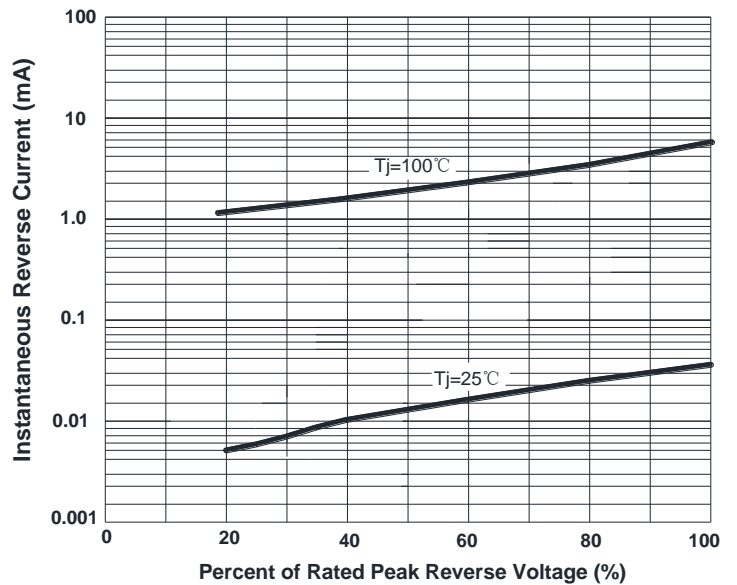
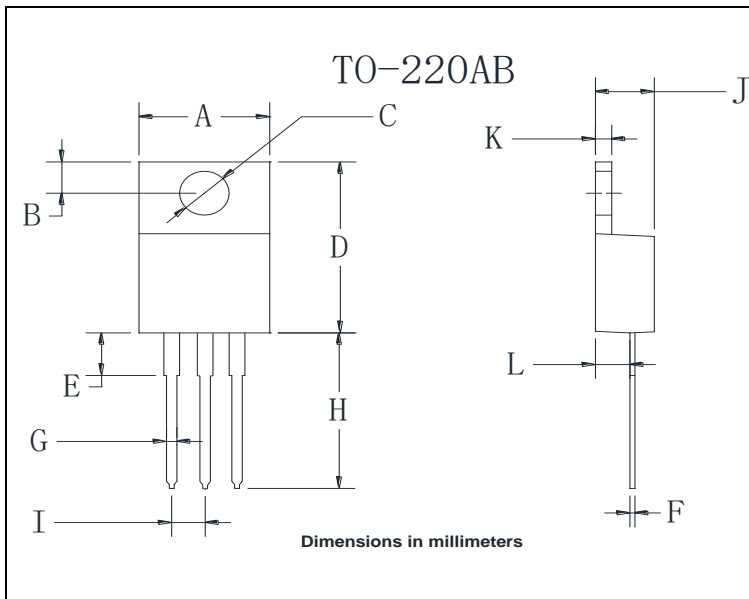


FIG4: Typical Reverse Characteristics



■Outline Dimensions



TO-220AB		
Dim	Min	Max
A	9.5	10.9
B	2.22	3.27
C	3.34	4.31
D	14.5	15.5
E	3.16	4.46
F	0.28	0.64
G	0.68	0.94
H	13.06	14.62
I	2.01	3.07
J	4.04	5.1
K	1.14	1.4
L	2.14	3.19

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